EM-NANO 2017 Program

		OPENING REMARKS (Main Hall)
09:00		Conference Chair
		PLENARY SESSION 1 (Main Hall)
09:15	PL1-1	Fiber Optic Nerve Systems for Structural Health Monitoring, Kazuo Hotate (Toyota Technological Institute, Japan)
10:00	PL1-2	Recent Progress in Inorganic Electro-Active Materials, Hideo Hosono (Tokyo Institute of Technology, Japan)
		Break
		PLENARY SESSION 2 (Main Hall)
11:15	PL2-1	3D Local Structure Science of Active-site by Atomic-Resolution Stereography and Holography, Hiroshi Daimon (Nara Institute of Science and Technology, Japan)
		FOCUS SESSION 1 (Main Hall)
		Chairperson: Mutsumi Kimura (Ryukoku University, Japan)
13:15	F1-1 (invited)	Organic Electrochemical Transistors as Bio-Sensors from Physics and Chemistry to Model Design, Yvan Bonnassieux, Anna Shirinskaya, Gilles Horowitz (LPICM, CNRS, Ecole Polytechnique, France)
13:45	F1-2 (invited)	Contact Effects in Organic Thin Film Transistors: Device Physics and Modeling, Guglielmo Fortunato, Matteo Rapisarda, Antonio Valletta, Luigi Mariucci (Consiglio Nazionale delle Ricerche - Institute for Microelectronics and Microsystems, Italy)
14:15	F1-3 (invited)	A Route toward Less-Lead or Lead-Free Perovskite Solar Cells , Meng Li, Zhao-Kui Wang, Liang-Sheng Liao (Soochow University, China)
14:45	F1-4 (invited)	PL Decay Imaging for Probing Carrier Behavior in Luminescence Polymer Thin Films, Takaaki Manaka, Mitsumasa Iwamoto (Tokyo Institute of Technology, Japan)
		Break
		FOCUS SESSION 2 (Main Hall)
		Chairperson: Koichi Maezawa (University of Toyama, Japan)
15:45	F2-1 (invited)	Renovation of Power Semiconductor Technology - From Silicon to Wide Bandgap Devices, Daisuke Ueda (Kyoto Institute of Technology, Japan)
16:15	F2-2 (invited)	High Performance III-V Nanowire Transistors , Erik Lind (Lund University, Sweden)
16:45	F2-3 (invited)	Femtosecond Slow-Motion of a Molecular Orbital in a Single Vibrating Molecule , Dominik Peller, Tyler L. Cocker, Ping Yu, Jascha Repp, Rupert Huber (University of Regensburg Germany)
17:15	F2-4 (invited)	Nanodiagnosis Platform Technology: Toward In-body Hospital , Takanori Ichiki ^{1,2} (¹ University of Tokyo, Japan, ² Kawasaki Institute of Industry Promotion, Japan)
		Break
		DOCTED CECCION 1 (10.00 - 10.20)
		POSTER SESSION 1 (18:00 - 19:30)

FOCUS SESSION 3 (Main Hall)

- Chairperson: Susumu Horita (Japan Advanced Institute of Science and Technology, Japan)
- 09:00 **F3-1 Ultimate Electronics with Control of Single Electrons**, Akira Fujiwara, Katsuhiko Nishiguchi, (invited) Gento Yamahata, Kensaku Chida (NTT Basic Research Laboratories, Japan)
- 09:30 **F3-2** Research Development on Device Fabrication Processes of Atomically Thin 2D Functional (invited) Films for Ubiquitous Sensing, Atsushi Ando (National Institute of Advanced Industrial Science and Technology, Japan)
- 10:00 **F3-3 Computational Nano-Materials Design and Realization: Defect and Impurity Control,**(invited) Hiroshi Katayama-Yoshida¹, Tetsuya Fukushima², Kazunori Sato², (¹University of Tokyo, Japan,

 ²Osaka University, Japan)

Break

FOCUS SESSION 4 (Main Hall)

- Chairperson: Atsushi Matsuda (National Institute of Advanced Industrial Science and Technology, Japan)
 - 11:00 **F4-1** Assessing the Limits and Possibility of Solar Cells, Pabitra K. Nayak (invited) (University of Oxford, UK)
 - 11:30 **F4-2 Solution-Processed Organic-Inorganic Perovskite Thin-Film Transistors with High Hole**(invited) **and Electron Mobilities**, Toshinori Matsushima^{1, 2}, Atula S. D. Sandayaka^{1, 2}, Chuanjiang Qin^{1, 2},
 Takashi Fujiwara³, Chihaya Adachi^{1, 2} (¹Kyushu University, Japan, ²JST, ERATO,
 Adachi Molecular Exciton Engineering Project, Japan, ³ISIT, Japan)
 - 12:00 **F4-3** Ferroelectric Photovoltaics Delivering Abnormally High Photovoltages, Yuji Noguchi¹, (invited) Ryotaro Inoue², Yuuki Kitanaka¹, Masaru Miyayama¹ (¹University of Tokyo, Japan, ²Nihon University, Japan)

POSTER SESSION 2 (12:30-14:00)

Break

PARALLEL SESSION 1

PA1-1: Organic Materials & Devices

Chairperson: Hiroyuki Okada (University of Toyama, Japan)

- 14:10 PA1-1-1 Fundamental Technology for Application of Organic Transistors to High Frequency (invited) Organic Transistors to High Frequency Operating Circuits, Masatoshi Kitamura (Kobe University, Japan)
- 14:40 PA1-1-2 Remaining Challenges in Organic Light-Emitting Diodes for Practical Use: Operational (invited) Lifetime and Color Purity, Hirohiko Fukagawa (NHK, Japan)
- 15:10 **PA1-1-3 Top-Gate Pentacene-Based OFET with α-Rubrene Gate Insulator,** Mizuha Hiroki, Yasutaka Maeda, Shun-ichiro Ohmi (Tokyo Institute of Technology, Japan)
- 15:30 PA1-1-4 Short-Circuit Current Enhancement in Photovoltaic-Based Organophosphate Pesticide
 Chlorpyrifos Sensor Using Surface Plasmon Resonance Effect, Treenet Thepudom^{1,2},
 Chutiparn Lertvachirapaiboon¹, Kazunari Shinbo¹, Keizo Kato¹, Futao Kaneko¹,
 Teerakiat Kerdcharoen², Akira Baba¹ (¹Niigata University, Japan, ²Mahidol University, Thailand)
- 15:50 PA1-1-5 Electronic Structures of bis(l,2,5-thiadiazolo)-p-quinobis(l,3-dithiole) (BTQBT) and Electrode Interface Measuring by Photoelectron Spectroscopy, N. Ohashi, S. Kobayashi, M. Hikasa, Y. Nakayama, Y. Watanabe (Tokyo University of Science, Japan)

PA1-2: Inorganic, Ferroelectric & Oxide materials

Chairperson: Hironori Fujisawa (University of Hyogo, Japan)

14:10 **PA1-2-1 Functional Properties of Ferroelectric Polymer and its Device Application**, (invited) Takashi Nakajima^{1, 2} (¹Tokyo University of Science, Japan, ²PRESTO, JST, Japan)

- 14:40 PA1-2-2 A Novel Power Device Materials of Corondum-Structured α-Ga₂O₃ Generated by MIST (invited) EPITAXY Technique, Kaneko Kentaro^{1, 2}, Shizuo Fujita¹, Toshimi Hitora² (¹Kyoto University, Japan, ²FLOSFIA, Japan)
- 15:10 **PA1-2-3 Diamond Epitaxy for High Power and High Temperature Electronics**, Franz A. Koeck¹, (invited) Maitreya Dutta^{1,2}, Raghuraj Hathwar¹, Mehdi Saremi¹, Xingye Wang¹, Brianna Eller¹, Manpuneet Kaur Benipal¹, Srabanti Chowdhury^{1,2}, Stephen M. Goodnick¹, Robert J. Nemanich¹ (¹Arizona State University, USA, ²University of California Davis, USA)
- 15:40 **PA1-2-4 Optimized Ascorbic Acid Fuel Cells with Graphene-coated Carbon Fiber Cloth,**Toshinari Doi¹, Kazuki Hoshi¹, Kazuo Muramatsu², Hisato Sumi², Yasushiro Nishioka¹,
 Satomitsu Imai¹ (¹Nihon University, Japan, ²Incubation Alliance Inc., Japan)

PA1-3: Photovoltaics I (Inorganic)

Chairperson: Atsushi Matsuda (National Institute of Advanced Industrial Science and Technology, Japan)

- 14:10 **PA1-3-1 Oxide Semiconductor Thin Films for Solar Cell Applications,** Toshihiro Miyata, (invited) Tadatsugu Minami (Kanazawa Institute of Technology, Japan)
- 14:40 **PA1-3-2 Optical Properties and Band Structures Cu(In,Ga)Se₂ and Cu-Deficient Phases,**(invited) **Cu(In,Ga)₃Se₅ and Cu(In,Ga)₅Se₈,** Takahiro Wada, Tsuyoshi Maeda (Ryukoku University, Iapan)
- 15:10 **PA1-3-3 First-Principles Study of Defect Formation in the Photovoltaic Semiconductor Cu₂ZnGeSe₄,** Hironori Nishihara, Tsuyoshi Maeda, Takahiro Wada (Ryukoku University, Japan)
- 15:30 PA1-3-4 Analysis for Leakage Currents within Unlaminated Photovoltaic-Module-Like Layer Stacks in a Cell-Level Potential-Induced Degradation Test, Seira Yamaguchi, Keisuke Ohdaira (Japan Advanced Institute of Science and Technology, Japan)
- 15:50 **PA1-3-5 Bending Cyclic Load Test for Crystalline Si Photovoltaic Modules,** Soh Suzuki^{1,2},
 Takuya Doi³, Atsushi Masuda³, Tadanori Tanahashi¹ (¹Espec Corp., Japan, ²Photovoltaic Power Generation Technology Research Association, Japan, ³National Institute of Advanced Industrial Science and Technology, Japan)

Break

PARALLEL SESSION 2

PA2-1: Thin-Film Transistors

Chairperson: Yukiharu Uraoka (Nara Institute of Science and Technology, Japan)

- 16:30 **PA2-1-1 Chemical Solution Process of In-Based Oxides and MoS₂ for Thin Film Transistors,** (invited) Eisuke Tokumitsu (Japan Advanced Institute of Science and Technology, Japan)
- 17:00 **PA2-1-2 Evaluation Stress Stabilities in Amorphous In-Ga-Zn-O Thin Film Transistors: Effect of** (invited) **Passivation with Si-based Resin,** Mototaka Ochi, Aya Hino, Hiroshi Goto, Kazushi Hayashi, Toshihiro Kugiyama (Kobe Steel Ltd., Japan)
- 17:30 **PA2-1-3 3-D Stacked Complementary Circuit with n-Type α-IGZO and p-Type F8T2 TFTs - Tolerant Characteristic against Temperature Change -** Takayuki Hasegawa¹, Masashi Inoue¹,
 Mutsumi Kimura¹, Kenji Nomura², Toshio Kamiya², Hideo Hosono² (¹Ryukoku Univeristy,
 Japan, ²Tokyo Institute of Technology, Japan)
- 17:50 PA2-1-4 A Novel Method for Low-Temperature Ultraviolet-Ozone Channel Activation of Amorphous In-Ga-Zn-O Thin Transistors, Michael Paul Jallorina, Juan Paolo Bermundo, Yasuaki Ishikawa, Yukiharu Uraoka (Nara Insititute of Science and Technology, Japan)

PA2-2: THz Electronics

Chairperson: Masahiko Tani (University of Fukui, Japan)

- 16:30 **PA2-2-1 Application of Terahertz Wave for Polymer Science,** Hiromichi Hoshina (invited) (RIKEN, Japan)
- 17:00 **PA2-2-2 Terahertz Oscillators and Receivers Using Electron Devices for Applications,** Safumi Suzuki, (invited) Masahiro Asada (Tokyo Institute of Technology, Japan)
- 17:30 **PA2-2-3 Study of Terahertz Radiation Propagation in Stratified GaAs/InGaAs/GaAs Structure for Detection Applications,** Anatoly Koval'chuk¹, Irina Khmyrova², Sergei Shapoval¹ (¹IMT RAS, Russia, ²University of Aizu, Japan)

17:50 PA2-2-4 Effects of Metal V-Grooved Waveguide Gap Width on High Efficient THz Waves
Generations Using Laser Chaos and Super Focusing, Fumiyoshi Kuwashima¹, Takuya Shirao¹,
Yusuke Akamine¹, Kazuyuki Iwao¹, Manatsu Ooi¹, Naoya Sakaue¹, Takurou Sirasaki¹,
Siori Gouda¹, Masahiko Tani², Kazuyoshi Kurihara², Kohji Yamamoto², Osamu Morikawa³,
Hideaki Kitahara², Makoto Nakajima⁴ (¹Fukui University of Technology, Japan, ²University of
Fukui, Japan, ³Chair of Liberal Arts, Japan Coast Guard Academy, Japan, ⁴Osaka University,
Japan)

PA2-3: Photovoltaics II (Organic)

Chairperson: Tatsuo Mori (Aichi Institute of Technology, Japan)

- 16:30 **PA2-3-1 A Hydrophobic Hole Transporting System to Improve Moisture Stability of Perovskite** (invited) **Solar Cells,** Lixin Xiao, Yingzhuang Ma, Lingling Zheng, Cuncun Wu (Peking University, China)
- 17:00 **PA2-3-2 Recent Progress in All Vacuum Processed Perovskite Solar Cells,** Chien-Yu Chen, (invited) Sheng-Yi Hsiao, Wei-Hung Lee, Wei-Lun Tsai, Hung-Yu Lin, Kai-Ming Chiang, Hao Wu Lin (National Ching Hua University, Taiwan)
- 17:30 PA2-3-3 Interface Engineering between Electron Transport Layer and Perovskite Layer for Perovskite Solar Cells, Takurou N. Murakami¹, Takashi Funaki¹, Tetsuhiko Miyadera¹, Ludmila Cojocaru², Said Kazaoui¹, Masayuki Chikamatsu¹, Hiroshi Segawa² (¹National Institute of Advanced Industrial Science and Technology, Japan, ²University of Tokyo, Japan)
- 17:50 PA2-3-4 Grating-Coupled Surface Plasmon Resonance Enhanced Organic Photovoltaic Devices Induced by Blu-Ray Disc Recordable and Blu-Ray Disc Grating Structures,

 Supeera Nootchanat^{1,2}, Apichart Pangdam^{1,2}, Ryousuke Ishikawa¹, Kanet Wongravee²,

 Kazunari Shinbo¹, Keizo Kato¹, Futao Kaneko¹, Sanong Ekgasit², Akira Baba¹ (¹Niigata University, Japan, ²Chulalongkorn University, Thailand)

Banquet (Yours Hotel) (18:30 - 20:30)

Wednesday, June 21, 2017

PARALLEL SESSION 3

PA3-1: Inorganic (Compound Semiconductors)

Chairperson: Joel T. Asubar (University of Fukui, Japan)

- 09:00 **PA3-1-1 Current Understanding and Challenges of Metal-Oxide-Semiconductor Gated GaN HFETs,** (invited) Milan Tapajna, Dagmar Gregusova, Karol Frohlich, Jan Kuzmik (Slovak Academy of Sciences, Slovakia)
- 09:30 **PA3-1-2 Progress of Wide Band Gap Power Devices,** Katsunori Ueno (invited) (Fuji Electric Co., Japan)
- 10:00 PA3-1-3 Enhancement-Mode AlGaN/GaN MIS-HEMTs with Recessed-Gate Structures Exhibiting High Threshold Voltage, Wataru Gamachi, Kotaro Ishii, Joel T. Asubar, Hirokuni Tokuda, Masaaki Kuzuhara (University of Fukui, Japan)

PA3-2: Bioelectronics

Chairperson : Ichiro Yamashita (Nara Institute of Science and Technology, Japan)

- 9:00 **PA3-2-1 Massive Parallel Operation of Bio-Substance by Microfluidic Techniques,** Yuzuru Takamura (invited) (Japan Advanced Institute of Science and Technology, Japan)
- 9:30 PA3-2-2 Biodegradable Neural Cell Culture Sheet Made of Poly (Lactic-Co-Glycolic Acid) Thin Film with Micropatterns of Polylysine Containing Laminin Layer, Yuki Nakamura, Shunpu Horiuchi, Eiki Koshinuma, Satomitsu Imai, Yasushiro Nishioka (Nihon University, Japan)
- 9:50 **PA3-2-3 Development of Graphene Oxide-poly(3,4-ethylenedioxythiophen) / poly(styrenesulfonate) Thin Film-Based Electrochemical-Surface Plasmon Resonance Immunosensor,**Chammari Pothipor^{1,2}, Kontad Ounnunkad², Chutiparn Lertvachirapaiboon¹, Kazunari Shinbo¹,
 Keizo Kato¹, Futao Kaneko¹, Akira Baba¹ (¹Niigata University, Japan, ²Chiang Mai University,
 Thailand)
- 10:10 **PA3-2-4 Highly Sensitive QCM Based Biosensor Using Au Dendrite Structure,** N. Asai, T. Yoshimura, T. Shimizu, S. Shingurbara, T. Ito (Kansai University, Japan)

		Chairperson: Akira Baba (Niigata University, Japan)	
9:00	PA3-3-1	Aspartame-Imprinted Conducting Polymer Pillar Arrays Using Insulating Inverse Silica	
	(invited)	Photonic Crystals, Jin Young Park (Kyungpook National University, Korea)	
9:30	PA3-3-2	Mechanical, Electronic Properties and Its Strain Engineering of Metal-Organic	
		Frameworks: A First-Principles Study, Xiaoyuan Wang ¹ , Fengpeng Zhao ¹ , Yabin Yan ^{1,2}	
		(¹ China Academy of Engineering Physics, China, ² Kyoto University, Japan)	
9:50	PA3-3-3	Synthesis of NiNW/ Cellulose Nano Hybrid via Liquid Phase Reduction,	
		Siti Rahmah Shamsuri ¹ , Eiichiro Matsubara ¹ , Shohei Shiomi ² (¹ Kyoto University, Japan, ² Kyoto	
		Municipal Institute of Industrial Technology and Culture, Japan)	
10:10	PA3-3-4	Acrobatic Crystals - Actuators on the Nanoscale, Jasminka Popovic ¹ , Ivor Loncaric ² ,	
		Zeljko Skoko ³ (¹ Rudjer Boskovic Institute, Croatia, ² Centro de Fisica de Materiales CFM/MPC,	
		Spain, ³ University of Zagreb, Croatia)	
		Break	
		PARALLEL SESSION 4	
		PA4-1 : Inorganic (Silicon)	
		Chairperson: Yukinori Ono (Shizuoka University, Japan)	
10:50		Single-Electron Tunneling via Dopant-Quantum-Dots Embedded in Silicon Nano-	
		Transistors and Nano-Diodes, Daniel Moraru, Michiharu Tabe (Shizuoka University, Japan)	
11:20	PA4-1-2	Formation of Al and Hf Germanates as Interlayers between High-κ Dielectrics and Ge	
		Substrates by Radical-Enhanced Atomic Layer Deposition, Daichi Yamada ¹ , Yohei Otani ¹ ,	
		Chiaya Yamamoto ² , Junji Yamanaka ² , Tetsuya Sato ² , Hiroshi Okamoto ³ , Yukio Fukuda ¹ (¹ Tokyo	
11.40	D4412	University of Science, Japan, ² University of Yamanashi, Japan, ³ Hirosaki University, Japan)	
11.40	PA4-1-3	Luminescent Si Nanomaterials Prepared from Agricultural Residues of Rice Husks, Kimihisa Matsumoto ¹ , Kazuhide Kamiya ¹ , Shigeki Kawabata ¹ , Shinya Suzuki ² (¹ Toyama	
		Prefectural University, Japan, ² Nagano National College of Technology, Japan)	
1		PA4-2 (Spintronics and Nanostructures)	
		Chairperson: Naotaka Uchitomi (Nagaoka University of Technology, Japan)	
ا 10:50	PA4-2-1	Spin Conversion Phenomena in Spintronics, Yoshichika Otani ^{1,2} , Kouta Kondou ² ,	
		Shutaru Karube ¹ , Junyeon Kim ² (¹ University of Tokyo, Japan, ² RIKEN, Japan)	
11:20		Simultaneous Measurement of Local and Non-Local Spin-Valve Signals in	
		MnAs/GaAs/InAs/GaAs(111)B Hybrid Structure, Md. Earul Islam, Kazuki Hayashida,	
		Masashi Akabori (Japan Advanced Institute of Science and Technology, Japan)	
11:40	PA4-2-3	Influence of Behaviour of Magnetic Particles in Ferrofluids against Alternating Magnetic	
		Fields on Harmonic Responses, Shoya Oda, Yoshitaka Kitamoto (Tokyo Institute of	
		Technology, Japan)	
		PA4-3 (Electronic Devices and Nanostructures) Chairpersons: Noriaki Ikenaga (Kanazawa Institute of Technology, Japan)	
		Takeshi Kawae (Kanazawa Institute of Technology, Japan)	
10:50	PA4-3-1	Nano-Level Analytical and Evaluation Techniques Essential to the Development of ULSI	
	(invited)	and Nano-Devices, Osamu Ueda (Kanazawa Institute of Technology, Japan)	
11:20	PA4-3-2	Electrical Characteristics of $SrBi_2Ta_2O_9$ Ferroelectric Thin Film Formed by Kr/O_2	
		Sputtering, B. J. Zeng ^{1,2} , Q. X. Peng ² , Y. C. Zhou ² , S. Ohmi ¹ (¹ Tokyo Institute of Technology,	
		Japan, ² Xiangtan University, China)	
11:40	PA4-3-3	Vacancy Induced Phonon Properties of Single Wall Carbon Nanotube,	
		Ashraful Hossain Howlader ¹ , Md. Sherajul Islam ² , Md. Rafiqul Islam ² , Ashraful Ghani Bhuiyan ²	
		(¹ Bangabandhu Sheikh Mujibur Rahman Science and Technology University, Bangladesh,	
		² Khulna University of Engineering and Technology, Bangladesh)	
		POSTER SESSION 3 (12:00 - 13:30)	
		Break	
	CLOSING REMARKS (14:00 - 14:20)		

Excursion (Ichijodani) (14:30 - 17:00)

PA3-3: Polymers and Nanostructures

EM-NANO 2017 POSTER SESSION

	Poster session 1 (June 19, 18:00 - 19:30)
PO1-1	Electrical Characterization of β-Ga ₂ O ₃ Single Crystal Substrate, Yoshitaka Nakano (Chubu
	University, Japan)
PO1-2	Electrical Characterization of p-GaN Film Homo-Epitaxially Grown on Free-Standing GaN
	Substrate, Yoshitaka Nakano (Chubu University, Japan)
PO1-3	Growth Nature of InSb Channel Layer on Heteroepitaxial Film of InGaSb Barrier Layer
	on GaSb/Si(111)-√3x√3-Ga Surface, A.A.Md.Monzur-Ul-Akhir, Masayuki Mori,
PO1-4	Koichi Maezawa (Toyama University, Japan) Study on High Frequency Loss in Coplanar Waveguides Fabricated on Si Substrate,
PO1-4	Kosuke Suzuki, Joel T. Asubar, Hirokuni Tokuda, Masaaki Kuzuhara (University of Fukui,
	Japan)
PO1-5	Primitive Study of VOC Sensor Using QCM Coated with Carbon Black, Takeshi Ito,
	Hiroshi Takahashi, Tomohiro Shimizu, Shoso Shingubara (Kansai University, Japan)
PO1-6	Optical and Radioluminescence Properties of Dy-doped 12CaO • 7Al ₂ O ₃ Electride Single
	Crystals, Narumi Kumamoto, Daisuke Nakauchi, Takumi Kato, Go Okada, Noriaki Kawaguchi,
	Takayuki Yanagida (Nara Institute of Science and Technology, Japan)
PO1-7	Liquid-Phase Synthesis of Vertically Aligned Carbon Nanotubes and Related
	Nanomaterials on Preheated Alloy Substrates, Kiyofumi Yamagiwa ¹ , Jun Kuwano ² (¹ Teikyo
	University of Science, Japan, ² Tokyo University of Science, Japan)
PO1-8	Fabrication of Lead-free Piezoceramics with Vertical MPB, Miao Yan, Tomoaki Karaki,
FO1-0	Tadasu Fujii (Toyama Prefectural University, Japan)
PO1-9	Luminescent and Scintillation Properties of Ce-doped Tb ₃ Ga _x Al _{5-x} O ₁₂ Single Crystals,
	Daisuke Nakauchi, Go Okada, Noriaki Kawaguchi, Takayuki Yanagida (Nara Institute of Science
	and Technology, Japan)
PO1-10	Enhanced Electrochemical Performance of Carbon Quantum Dots-Polyaniline Hybrid,
	Zhichao Zhao, Yibing Xie (Southeast University, China)
PO1-11	Fabrication and Supercapacitor Behavior of Phosphomolybdic Acid/Polyaniline/Titanium
	Nitride Core-Shell Nanowire Array, Lu Lu, Yibing Xie (Southeast University, China)
PO1-12	Growth of Langasite-type Ca ₃ NbGa _{3-x} Al _x Si ₂ O ₁₄ Single Crystals, Yuki Kiyohara,
	Masakazu Kobayashi, Tomoaki Karaki, Tadashi Fuji (Toyama Prefectural University, Japan)
PO1-13	Doping Nitrogen in InGaZnO Thin Film Transistor with Double Layer Channel Structure,
	Sheng-Po Chang (National Cheng Kung University, Taiwan)
PO1-14	The Charge-Discharge Characteristics of Mg-Zn-Al Powder with Ag Nanoparticles-
	Modified at High Temperature Environment, Kuan-Jen Chen, Fei-Yi Hung, Truan-Sheng Lui
	Tung-Hsuan Hsiao (National Cheng Kung University, Taiwan)
PO1-15	Preparation of Cu ₂ SnS ₃ (CTS) Thin Film by Photo Chemical Deposition, Amane Abe ¹ ,
	Katsuhiko Moriya ¹ , Takeshi Houga ¹ , Kunihiko Tanaka ² (¹ National Institute of Technology,
	Tsuruoka College, Japan, ² Nagaoka University of Technology, Japan)
PO1-16	Effect of Annealing Conditions of Cu ₂ ZnSnS ₄ Thin Films Prepared by Dip Coating,
	Yusuke Togashi ¹ , Katsuhiko Moriya ¹ , Takeshi Houga ¹ , Kunihiko Tanaka ² (¹ National Institute of
	Technology, Tsuruoka College, Japan, ² Nagaoka University of Technology, Japan)
PO1-17	Luminescence Characterizations of Sc-doped Al ₂ O ₃ Ceramics Prepared by Spark Plasma
F 0 1-17	Sintering Method for Radiation Detectors, Nurul Athirah Noor Azman, Takumi Kato,
	Go Okada, Noriaki Kawaguchi, Takayuki Yanagida (Nara Institute of Science and Technology,
	Japan)
PO1-18	Formation of Graphitic Carbon Nitride Thin-Film on Sapphire Substrate, Maito Kosaka,
1 01-10	Noriyuki Urakami, Yoshio Hashimoto (Shinshu University, Japan)
	1.011 of the control

PO1-19	Tuning the Molecular Chain Distance to Improve Memory Window of Polyimide-Based
	Resistive Switching Memory, Guan-Wei Lin, Min-Fang Kao, Chi-Chang Wu, Wen-Luh Yang
	(Feng Chia University, Taiwan)
PO1-20	Luminescence Properties of Organic-Inorganic Layered Perovskite-Type Compounds
	under Vacuum Ultraviolet Irradiation, Naoki Kawano ¹ , Masanori Koshimizu ² ,
	Yutaka Fujimoto ² , Go Okada ¹ , Noriaki Kawaguchi ¹ , Takayuki Yanagida ¹ , Keisuke Asai ² (¹ Nara
	Institute of Science and Technology, Japan, ² Tohoku University, Japan)
PO1-21	Preparation of 0.09BaZrO ₃ -0.9025(K _{0.45} Na _{0.5} Li _{0.05})NbO ₃ -0.0075(La _{0.5} Na _{0.5})TiO ₃
PO1-21	
	Piezoelectric Thin Films from Precursor Solution by Pechini Method, Liqiang Liu ¹ ,
	Tomoaki Karaki ¹ , Tadashi Fujii ¹ , Yuichi Sakai ² (¹ Toyama Prefectural University, Japan,
	² Toyama Industrial Technology Center, Japan)
PO1-22	Visualization Method of Blood Flowing by Laser Doppler Velocimetry Using Speckle and
	Fringe Pattern, Shunsuke Akiguchi ¹ , Tomoaki Kyoden ¹ , Shoji Naruki ¹ , Tomoki Tajiri ¹ ,
	Tsugunobu Andoh ² , Hiroki Ishida ³ , Tadashi Hachiga ¹ (¹ National Institute of Technology,
	Toyama College, Japan ² University of Toyama, Japan, ³ Okayama University of Science, Japan)
PO1-23	Multi-photon Confocal Microscope Evaluation of Fluorescent Centres in Ag-activated
	Phosphate Glass Irradiated with Heavy Charged Particles, Toshio Kurobori ¹ , Wataru Kada ² ,
	Taichi Shirao ³ , Takahiro Satoh ⁴ (¹ Kanazawa University, Japan, ² Gunma University, Japan,
	³ Nikon Instech Co., Ltd., Japan, ⁴ Takasaki Advanced Radiation Research Institute, Japan)
PO1-24	Bulk-Related Current Collapses in Carbon-Doped AlGaN/GaN/GaN:C Hetero-Structures
	Grown on Si Substrates, Akihito Chikamatsu, Yoshitaka Nakano (Chubu University, Japan)
PO1-25	Low-Temperature Solution Processed Indium Oxide Using Ultraviolet Annealing,
	Yuuki Yoshimoto, Jinwang Li, Tatsuya Shimoda (Japan Advanced Institute of Science and
	Technology, Japan)
PO1-26	Study of Fabricating Orientated Lead-Free Piezoceramics Using Plate-Like Powders,
	Yoshiaki Ido, Yao Lu, Tomoaki Karaki, Tadashi Hujii (Toyama Prefectural University, Japan)
PO1-27	Estimation of Activation Energy of Si-doped β-Ga ₂ O ₃ Thin Films, Satoshi Itoh ¹ ,
	Iwan Dwi Antoro ¹ , Takashi Nakajima ² , Takeshi Kawae ¹ (¹ Kanazawa University, Japan, ² Tokyo
DO4 20	University of Science, Japan)
PO1-28	Composites of Hydroxyethyl Cellulose and M ²⁺ Chelate Complexes as an Effective
	Electron-injection Layer for Polymer Light-emitting Diodes, Yun Chen, Cheng-Liang Wu, Chih-Yang Lin (National Cheng Kung University, Taiwan)
- DO4 00	
PO1-29	Simple Quantization Method of Localized Surface Plasmon for Quantum Plasmonics, Hisaki Oka, Yasuo Ohdaira (Niigata University, Japan)
PO1-30	Surface Second Harmonic Generation (SHG) on the Au/TiO ₂ (320) Interface and Bare TiO ₂
	(320), Haque MD Ehasanul ¹ , Daiki Kobayashi ¹ , Yuki Tomatsu ¹ , Khuat Thi Thu Hien ¹ ,
	Goro Mizutani ¹ , Harvey N. Rutt ² (¹ Japan Advanced Institute of Science and Technology, Japan,
	² University of Southampton, UK)
PO1-31	High-Temperature Annealing Effect of Ferromagnetic ZnSnAs ₂ Thin Films Heavily Doped
	with Mn, Y. Minamizawa ¹ , T. Kitazawa ¹ , S. Hidaka ¹ , H. Toyota ¹ , S. Nakamura ² ,
	B. Mehdiyev ¹ , N. Uchitomi ¹ (¹ Nagaoka University of Technology, Japan, ² Aoyama Gakuin
	University, Japan)
PO1-32	Porous Silicon Film Formation from Silicon-Nanoparticle Inks: the Possibility of Influences
	of van der Waals Interactions on Uniform Film Formation, Kazuki Tanaka, Wataru Nagoya,
	Kazuya Moriki, Seiichi Sato (University of Hyogo, Japan)

PO1-33	Improvement of Wettability of Porous Si by Carboxylate Termination, M. Sakakibara ¹ , K. Matsumoto ¹ , K. Kamiya ¹ , S. Kawabata ¹ , M. Inada ² , S. Suzuki ³ (¹ Toyama Prefectural
	University, Japan, ² Kansai University, Japan, ³ Nagano National College of Technology, Japan)
PO1-34	Influence of Ambient Gas on the Electrical Conduction of Porous Silicon films Produced from Silicon Nanoparticle Inks, Wataru Nagoya, Kazuki Tanaka, Kazuya Moriki, Seiichi Sato (University of Hyogo, Japan)
PO1-35	Er-doped ZnO Films Deposited by an Alternative Pulsed Laser Deposition, Satoru Yamada
	Souki Urashita, Hiroto Kawae, Daiki Okada, Satoru Seto (National Institute of Technology,
	Ishikawa College, Japan)
PO1-36	Fabrication of ZnO Multi-Layer Transparent Conductive Films by Spin-Coating Method
	and Discussion on Improving Their Performance, Yusuke Morita, Naoki Ohtani (Doshisha University, Japan)
PO1-37	Blue-color Photoluminescence from Natural Pigments Extracted from Fraxinus
101-07	Lanuginosa, Yusuke Kinou, Naoki Ohtani (Doshisha University, Japan)
PO1-38	Antioxidant Effect of β-Carotene and Lutein Isolated and Purified from Spinach on
	Photoluminescence Lifetime of Organic Emissive Materials, Shun Imada, Takato Ito,
	Naoki Ohtani (Doshisha University, Japan)
PO1-39	Fabrication of Emissive Thin Films Using Nano-amorphous Graphitic Carbon Nitride
	Powders, Takahiro Watanabe ¹ , Masaaki Hirai ² , Ken-ichi Takarabe ² , Naoki Ohtani ¹ (¹ Doshisha
	University, Japan, ² Okayama University of Science, Japan)
PO1-40	Investigation of Photoluminescence from Cu ₂ ZnSnS ₄ Depending on Growth Temperature,
	Yoshiharu Takamatsu, Kunihiko Tanaka (Nagaoka University of Technology, Japan)
PO1-41	Fabrication of Core-Shell Quantum Dot Films by a Spin-Coating Method and Their
	Application to Light-Emitting Diodes, Chisato Konishi, Naoki Ohtani (Doshisha University, Japan)
PO1-42	Influence of Au Nanoparticles on Magnetic Characteristics in TbFeCo/Au Nanostructures
	Ryousuke Hara ¹ , Haruki Yamane ² , Masanobu Kobayasi ¹ , Xiaoxi Liu ³ , Akimitsu Morisako ³ ,
	Yukiko Yasukawa ¹ (¹ Chiba Institute of Technology, Japan, ² Akita Industrial Technology Center
	Japan, ³ Shinshu University, Japan)
PO1-43	Analysis of Optics Properties and Carrier Transport in a Biased GaAs/AlAs Asymmetric
	Quintuple-Quantum-Well Superlattice, Kousuke Yoshida ¹ , Makoto Hosoda ² ,
	Kouichi Akahane ³ , Naoki Ohtani ¹ (¹ Doshisha University, Japan, ² Shizuoka University, Japan,
	³ National Institute of Information and Communications Technology, Japan)
PO1-44	Platinum-Free, Carbon-Based Materials as Efficient Counter Electrodes for Dye-Sensitize
10144	Solar Cells, Hendri Widiyandari ¹ , Adi Prasetio ¹ , Agus Purwanto ² , Agus Subagio ¹ ,
	Muhammad Hilmy Alfaruqi ³ (¹ Diponegoro University, Indonesia, ² Sebelas Maret University,
	Indonesia, ³ Chonnam National University, Korea)
DO4 45	
PO1-45	Diffusion of Hydroxyl Groups Through Binding Interface between Hydroxyl-Containing
	and Oxygen-Deficient Silica Glasses, Yu Arakawa ¹ , Naoya Sato ¹ , Nobu Kuzuu ¹ ,
	Hideharu Horikoshi ² , Hiroki Sakakibara ¹ (¹ University of Fukui, Japan, ² Tosoh SGM Corp.,
	Japan)
PO1-46	
PO1-46	Japan) Fabrication of H-Terminated Diamond MISFET with Al ₂ O ₃ as Buffer Layer, S. Shoji, H. Furuichi, T. Kawae (Kanazawa University, Japan)
PO1-47	Japan) Fabrication of H-Terminated Diamond MISFET with Al ₂ O ₃ as Buffer Layer, S. Shoji, H. Furuichi, T. Kawae (Kanazawa University, Japan) Fabrication of Carbon Nitride-based Emissive Thin Films by Wet Process Using Annealed Melamine, Katsuya Wada, Naoki Ohtani (Doshisha University, Japan)
	Japan) Fabrication of H-Terminated Diamond MISFET with Al ₂ O ₃ as Buffer Layer, S. Shoji, H. Furuichi, T. Kawae (Kanazawa University, Japan) Fabrication of Carbon Nitride-based Emissive Thin Films by Wet Process Using Annealed
PO1-47	Japan) Fabrication of H-Terminated Diamond MISFET with Al ₂ O ₃ as Buffer Layer, S. Shoji, H. Furuichi, T. Kawae (Kanazawa University, Japan) Fabrication of Carbon Nitride-based Emissive Thin Films by Wet Process Using Annealed Melamine, Katsuya Wada, Naoki Ohtani (Doshisha University, Japan)

PO1-49	Diffusion Coefficient of Hydroxyl Group in Vitreous Silica, Naoya Sato ¹ , Yu Arakawa ¹ ,
	Nobu Kuzuu ¹ , Hideharu Horikoshi ² , Hiroki Sakakibara ¹ , Naohiro Horii ³ (¹ University of Fukui,
	Japan, ² Tosoh SGM Corp., Japan, ³ National Institute of Technology, Fukui College, Japan)
PO1-50	Preparation of Transparent CuI-CuBr Alloy Thin Films with Solution Processing,
	Taiga Harada ¹ , Shoko Tao ¹ , Toshiki Imamura ¹ , Katsuhiko Moriya ² , Nobuo Saito ¹ ,
	Kunihiko Tanaka ¹ (¹ Nagaoka University of Technology, Japan, ² National Institute of Technology,
	Tsuruoka College, Japan)
PO1-51	Cl-free CZTS Thin Film Solar Cell Fabricated by Non-Vacuum Process, Atsushi Munemura,
	Kyouhei Yamamoto, Kunihiko Tanaka (Nagaoka University of Technology, Japan)
PO1-52	Effect of Air Assisted Flow on Organic Perovskite Solar Cells Fabricated by One Step Spin-
	Coating Method, Hiroyuki Okada, Kenta Saito, Vincent Obiozo Eze, Yoshiyuki Seike,
	Tatsuo Mori (Aichi Institute of Technology, Japan)
PO1-53	Optical Properties of Wannier excitons in Closely Located Quantum Wells in Organic-
	Inorganic Layered Perovskite-Type Compounds, Daiki Tajima, Masanori Koshimizu,
	Yutaka Fujimoto, Keisuke Asai (Tohoku University, Japan)
PO1-54	Electronic Structure and Magnetic Properties of Mn-doped Perovskites for Solar Cell
	Applications, Atsushi Suzuki, Takeo Oku (University of Shiga Prefecture, Japan)

	Poster session 2 (June 20, 12:30 - 14:00)
PO2-1	Electrospinning of Silver/Polymer Composite Nanofiber Mats for Lightweight and Flexible Electrodes, Han-Hsuan Chen, Jyun-You Su, Chien-Tin Lin, Yu-Yu Cho, Changshu Kuo (National Cheng Kung University, Taiwan)
PO2-2	Study of Organic/Inorganic Polymer/Quantum Dot Nanocomposite for Lighting and Displays, Hsueh-Shih Chen, Wen Hsin Tsai, Shang-Chieh Huang, Chang-Wei Yeh, Guan-Hong Chen (National Tsing Hua University, Taiwan)
PO2-3	Scintillation and Dosimetric Properties of Tb-doped LiCaAlF ₆ Single Crystals, Noriaki Kawaguchi ¹ , Naoki Kawano ¹ , Go Okada ¹ , Kentaro Fukuda ² , Takayuki Yanagida ¹ (¹ Nara Institute of Science and Technology, Japan, ² Tokuyama Corp., Japan)
PO2-4	Preparation of B1-(Cr,Ga)N Thin Films by Pulsed Laser Deposition, Yusei Mizuno, Tsuneo Suzuki, Tadachika Nakayama, Hisayuki Suematsu (Nagaoka University of Technology, Japan)
PO2-5	Preparation of Ge doped Cu ₂ ZnSn(S,Se) ₄ Absorber Thin Films, Daiki Miyazawa ¹ , Mitsuki Shinohara ¹ , Noritaka Momose ¹ , Myo Than Htay ² , Yoshio Hashimoto ² , Kentaro Ito ² (¹ National Institute of Technology, Nagano College, Japan, ² Shinshu University, Japan)
PO2-6	Preparation of Aluminum Nanostructured Materials by a Two Step Heating Process in Spark Plasma Sintering, Tosiki Honma ¹ , Itsuhiko Hirota ¹ , Yoshinori Tokoi ¹ , Naritoshi Aoyagi ¹ , Hisayuki Suematsu ² (¹ National Institute of Technology, Nagaoka College, Japan, ² Nagaoka University of Technology, Japan)
PO2-7	Characterization of Mn-doped ZnSnAs ₂ Thin Films Below the Magnetic Percolation Threshold, S. Saito ¹ , M. Ogo ¹ , S. Hidaka ¹ , H. Toyota ¹ , M. Akabori ² , B. Mehdiyev ¹ , N. Uchitomi ¹ (¹ Nagaoka University of Technology, Japan, ² Japan Advanced Institute of Science and Technology, Japan)
PO2-8	Structural and Thermoelectric Properties of Bismuth Telluride Nanoplate Thin Films with and without Carbon Nanotubes, Yuichi Hosokawa, Kodai Wada, Masaki Tanaka, Koji Tomita, Masayuki Takashiri (Tokai University, Japan)
PO2-9	Control of Particle Size and Phase by Dwell-Time on Pulsed Wire Discharge, Taiga Murayama, Yoshinori Tokoi (National Institute of Technology, Nagaoka College, Japan)

PO2-10	Planar Perovskite Solar Cells Employing CuSCN/ NPB Bilayer Structure as Hole Transport
	Layers, Zong-Liang Tseng, Lung-Chien Chen, Yu-Jen Lin and Yan-Rong Hung (National Taipei
	University of Technology, Taiwan)
	(Withdrawn) Towards Colloidal Spintronics: Rashba Spin-Orbit Coupling in PbS
	Nanosheets, Mohammad Mehdi Ramin Moayed, Thomas Bielewicz, Martin Sebastian Zoellner,
	Carmen Herrmann, Christian Klinke (University of Hamburg, Germany)
PO2-12	Computer Aided-Molecular Design of Functionalized Fullerenes and Graphenes,
	Hiroto Tachikawa, Tetsuji Iyama, Hiroshi Kawabata (Hokkaido University, Japan)
PO2-13	Density Functional Theory (DFT) Study on the Interaction of H ₂ with Metal Atoms on
	Graphene Surface, Tetsuji Iyama, Takahiro Fukuzumi, Hiroto Tachikawa (Hokkaido University,
	Japan)
PO2-14	Density Functional Theory (DFT) Study on the Interaction of Hydrogen Atom with
	Graphene Nano-Flakes, Hiroshi Kawabata, Tetsuji Iyama, Hiroto Tachikawa (Hokkaido
	University, Japan)
PO2-15	Optimization of Film Thickness in Organic Multi-function Diodes Based on
	Rubrene/PTCDI-C13 Stack, Masahiro Yamada, Shigeki Naka, Hiroyuki Okada (University of
	Toyama, Japan)
PO2-16	Organic Light-Emitting Diodes with Printed Narrow Ag Auxiliary Wire, Hiroki Kuroda ¹ ,
	Shigeki Naka ¹ , Hiroyuki Okada ¹ , Hiroyuki Kitazawa ² , Masahito Okumura ³ , Tatsuya Nishimura ³
	(¹ University of Toyama, Japan, ² SHASHIN KAGAKU CO., LTD., Japan, ³ SK-Electronics CO.,
	LTD., Japan)
PO2-17	Characterizing In/Ga-doped ZnO Fabricated Using Sol-Gel Synthesis Method,
1 02 17	Ji-Siou Huang, Leo Chau-Kuang Liau (Yuan Ze University, Taiwan)
PO2-18	Effect of Electrochemical Processing on the Fabrication of Cu ₂ O p-n Homojunction Diode,
	Chin-Ming Chang, Leo Chau-Kuang Liau (Yuan Ze University, Taiwan)
PO2-19	CNT/Graphite/ZnO Composite for Supercapacitor Electrode, Agus Subagio ¹ ,
. 02 .0	
	Istajib A. Hikam ¹ , Alfin Darari ¹ , Priyono ¹ , Pardoyo ¹ , Ahmad Subhan ² (¹ Diponegoro University,
	Japan, ² Center of Physics Research, LIPI, Japan)
PO2-20	Preparation of Cu ₂ (Sn,Si)S ₃ Thin-film Solar Cells by Cu-Sn-Si Simultaneous Sputtering,
	Masaki Aida ¹ , Yusuke Wakui ¹ , Noritaka Momose ¹ , Myo Than Htay ² , Yoshio Hashimoto ² ,
	Kentaro Ito ² (¹ National Institute of Technology, Nagano College, Japan, ² Shinshu University,
	Japan)
PO2-21	Density Functional Theory (DFT) Study on the Radical-Functionalized Graphenes and
F-02-21	Fullerenes, Shigeaki Abe ¹ , Yuko Era ¹ , Yukari Nakagawa ¹ , Mariko Nakamura ² , Teruo Kusaka ¹ ,
	Satoshi Inoue ¹ , Yasuhiro Yoshida ¹ , Hiroto Tachikawa ¹ (¹ Hokkaido University, Japan, ² Kyushu
	University of Health and Welfare, Japan)
PO2-22	Highly Crystalline Li ₄ Ti ₅ O ₁₂ Material Synthesized using Salt Assisted-Solid State Reaction
	Method, Agus Purwanto ¹ , Hendri Widiyandari ² , Alfa Tegar Augusta ¹ , Rizqa Amalia Devi ¹ ,
	Arif Jumari ¹ (¹ Sebelas Maret University, Indonesia, ² Diponegoro University, Indonesia)
DO0 00	
PO2-23	Fabrication of Mold and Stamp for Micro Contact Print to Realize Flexible Liquid Crystal
DO2 24	Devices, Masaki Kataoka, Hiroyuki Okada (University of Toyama, Japan)
PO2-24	Improved Performance of Multilayer Inverted Polymer Light-Emitting Diode with a
	Tantalum Oxide Nanosheet Electron Injection Layer, Eiji Itoh, Taichi Hasebe (Shinshu University, Japan)
DO2 25	University, Japan) Estimation of Courier Mobility of Ougania Somiconductor Films in MIS Diedes Consisting
PO2-25	Estimation of Carrier Mobility of Organic Semiconductor Films in MIS Diodes Consisting
	of High-κ Oxide/Organic Semiconductor Double Layers, Naoya Tyosei, Eiji Itoh (Shinshu University, Japan)
	University, Japan)

PO2-26	Fabrication of Three-Terminal Hanle Devices and its Evaluation Using Mn-Doped ZnSnAs ₂
	Thin Film Grown on InP(001) Substrates, Shiro Hidaka ¹ , Hideyuki Toyota ¹ ,
	Masashi Akabori ² , Naotaka Uchitomi ¹ (¹ Nagaoka University of Technology, Japan, ² Japan
	Advanced Institute of Science and Technology, Japan)
PO2-27	Al ₂ O ₃ Passivation of Amorphous IGZO Thin Film Transistors through Atomic Layer
	Deposition using Dimethylaluminum Hydride as Precursor, Dianne Corsino ¹ ,
	Juan Paolo Bermundo ¹ , Kiyoshi Takahashi ² , Yasuaki Ishikawa ¹ , Yukiharu Uraoka ¹ (¹ Nara
	Institute of Science and Technology, Japan, ² Nippon Aluminum Alkyls, Ltd., Japan)
PO2-28	Formation Mechanism of Graphene-on-Diamond Using Nickel as a Catalyst,
. 02 20	Yutaro Katagiri ¹ , Shohei Kanada ¹ , Taira Tabakoya ¹ , Masatsugu Nagai ¹ , Takahiro Yamamoto ¹ ,
	Toshiharu Makino ² , Satoshi Yamasaki ² , Tsubasa Matsumoto ¹ , Norio Tokuda ¹ , Takao Inokuma ¹
	(¹ Kanazawa University, Japan, ² National Institute of Advanced Industrial Science and
	Technology, Japan)
PO2-29	Effects of Non-Toxic Metal Element Addition into Perovskite Photovoltaic Devices,
	Yasuhiro Shirahata, Takeo Oku (University of Shiga Prefecture, Japan)
PO2-30	Formation of Epitaxial ReS ₂ (0001) Thin-Film on c-Plane Sapphire Substrate,
	Noriyuki Urakami, Tetsuya Okuda, Yoshio Hashimoto (Shinshu University, Japan)
PO2-31	Photoluminescence Properties of Ce ³⁺ and Eu ²⁺ Co-Doped CaY ₂ Si ₂ S ₈ Phosphors,
	Yasuhiro Nemoto, Tomu Tanabe, Ariyuki Kato (Nagaoka University of Technology, Japan)
PO2-32	Phase Control of Eu-doped Sr ₂ SiO ₄ Phosphor by Eu Concentration and Sintering
	Temperature, Siti Sarina Binti Nasir, Kouta Yakura, Noriyuki Horiuchi, Ariyuki Kato (Nagaoka
	University of Technology, Japan)
PO2-33	Structural and Optical Properties of Silicon Spheres and Anti-Reflection Films for
	Spherical Silicon Solar Cells, Yasuhiro Shirahata ¹ , Takeo Oku ¹ , Youichi Kanamori ² ,
	Mikio Murozono ² (¹ University of Shiga Prefecture, Japan, ² Clean Venture 21 Corp., Japan)
PO2-34	Effect of ¹⁰ B Isotope Doping on Phonon Modes of 2D h-BN, Md. Sherajul Islam ¹ ,
	Akihiro Hashimoto ² (¹ Khulna University of Engineering and Technology, Bangladesh,
	² University of Fukui, Japan)
PO2-35	The Nozzle Shape Stereographic Microstructure Produced by Direct Laser writing on Dual
	Layer Resists, Chun-Ming Chang, Wen-Tse Hsiao, Chih-Chung Yang, Shih-Feng Tseng,
	Donyau Chiang (National Applied Research Laboratories, Taiwan)
PO2-36	Particle Size Control of Magnesium Submicron Particles Prepared by Pulsed Wire
	Discharge , Nguyen Duy Hieu ¹ , Yoshinori Tokoi ² , Kenta Tanaka ¹ , Tsuneo Suzuki ¹ ,
	Tadachika Nakayama ¹ , Hisayuki Suematsu ¹ , Koichi Niihara ¹ (¹ Nagaoka University of
	Technology, Japan, ² Nagaoka National College of Technology, Japan)
PO2-37	Fabrication of SnS Films Deposited by the Sol-Gel Method, Hiroto Oomae ¹ , Takahito
	Eguchi ¹ , Kunihiko Tanaka ² (¹ National Institute of Technology, Kushiro College, Japan, ² Nagaoka
	University of Technology, Japan)
PO2-38	NIR-Responsive Photocatalytic Activity and Mechanism of Upconversion
	Nanoparticles/Anatase Phase of TiO ₂ Aerogel, Fu-Chih Li, Yoshitaka Kitamoto (Tokyo
	Institute of Technology, Japan)
PO2-39	Demonstration of Motion Control of Micro ZrO ₂ Particles in Uniform/Non-Uniform
	Electric Field, Genki Onishi, Naoto Matsutani, Tadachika Nakayama, Tsuneo Suzuki,
	Hisayuki Suematsu, Koichi Niihara (Nagaoka University of Technology, Japan)

PO2-40	Optical and Electrical Characteristics of ZnO Nanoparticle Electrode and Silica-Based Gel
	Type Solvents for Solid-State Electroluminescence Cells, Buranid Dammai ¹ ,
	Somehai Arunrungrusmi ¹ , Pakpoom Chansri ¹ , Toshifumi Yuji ² , Narong Mungkung ¹ (¹ King's
	Mongkut University of Technology Thonburi, Thailand, ² University of Miyazaki, Japan)
PO2-41	Effects of Sequential Ultraviolet and Thermal Treatment on Performances and Stability in
	High-Mobility ZnON TFT, Hwan-Seok Jeong, Dae-Hwan Kim, Hyuck-In Kwon (Chung-Ang
	University, Japan)
PO2-42	Influence of Moisture on the Electrical instability of Zinc Oxynitride Thin-Film Transistors
	Dae-Hwan Kim, Hwan-Seok Jeong, Hyuck-In Kwon (Chung-Ang University, Korea)
PO2-43	Improved Heterodyne Terahertz Electro-Optic Sampling by Using DAST Crystal,
	Hiroyuki Kato ¹ , Hideaki Kitahara ¹ , Daiki Goto ¹ , Takuro Yasumoto ¹ , Kohji Yamamoto ¹ ,
	Takashi Furuya ¹ , Takashi Notake ² , Hiroaki Minamide ² , Michael Bakunov ³ , Masahiko Tani ¹
	(¹ University of Fukui, Japan, ² RIKEN, Japan, ³ University of Nizhny Novgorod, Russia)
	(University of Fukur, Japan, Kiken, Japan, University of Nizhiny Novgorod, Russia)
PO2-44	Investigation of Dye-Sensitized Solar Cell Used by MnO ₂ :C Counter Electrode,
	Noritsugu Kamata ¹ , Pakpoom Chansri ¹ , Somchai Arunrungrusmi ¹ , Toshifumi Yuji ² ,
	Narong Mungkung ¹ (¹ King's Mongkut University of Technology Thonburi, Thailand, ² Universit
	of Miyazaki, Japan)
PO2-45	Time-Resolved Differential Transmissivity in CH ₃ NH ₃ PbI ₃ and CH ₃ NH ₃ Pb(I, Cl) ₃ Thin
	Films, Ryuichi Ito, Yuto Yamazaki, Takayuki Makino (University of Fukui, Japan)
PO2-46	Fabrication of the Mechanism for Mixing Micro-Fluid by Using the Micro-Pump,
	K. Moriya ¹ , N. Matsutani ¹ , Maria Guadalupe del Rocio Herrera Salazar ² , H. Suematsu ¹ ,
	T. Nakayama ¹ , T. Suzuki ¹ , K. Nijhara ¹ (¹ Nagaoka University of Technology, Japan, ² Aarhus
	T. Nakayama ¹ , T. Suzuki ¹ , K. Niihara ¹ (¹ Nagaoka University of Technology, Japan, ² Aarhus University, Denmark)
D00 47	University, Denmark)
PO2-47	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃
PO2-47	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa,
PO2-47	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan)
PO2-47	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa,
	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan)
	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-
	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae,
PO2-48	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea)
PO2-48	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten
PO2-48	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim,
PO2-48	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea)
PO2-48	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure,
PO2-48	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba,
PO2-49 PO2-50	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan)
PO2-49 PO2-50	Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of
PO2-49 PO2-50	Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of p-Type SnO Thin-Films for Thin-Film Transistor Applications, Sang-Dae Bae,
PO2-49 PO2-50 PO2-51	Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of p-Type SnO Thin-Films for Thin-Film Transistor Applications, Sang-Dae Bae, Soo-Hun Kwon, Hwan-Seok Jeong, Hyuck-In Kwon (Chung-Ang University, Korea) CO ₂ Laser-Induced Breakdown Spectroscopy Applied to Cr Speciation Analysis Using
PO2-49 PO2-50 PO2-51	Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of p-Type SnO Thin-Films for Thin-Film Transistor Applications, Sang-Dae Bae, Soo-Hun Kwon, Hwan-Seok Jeong, Hyuck-In Kwon (Chung-Ang University, Korea) CO ₂ Laser-Induced Breakdown Spectroscopy Applied to Cr Speciation Analysis Using Surfactant, Takuya Matsumoto, Seiji Kitayama, Kazuma Takauchi, Kazuyoshi Kurihara
PO2-49 PO2-50 PO2-51	Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of p-Type SnO Thin-Films for Thin-Film Transistor Applications, Sang-Dae Bae, Soo-Hun Kwon, Hwan-Seok Jeong, Hyuck-In Kwon (Chung-Ang University, Korea) CO ₂ Laser-Induced Breakdown Spectroscopy Applied to Cr Speciation Analysis Using Surfactant, Takuya Matsumoto, Seiji Kitayama, Kazuma Takauchi, Kazuyoshi Kurihara (University of Fukui, Japan)
PO2-49 PO2-50 PO2-51	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of p-Type SnO Thin-Films for Thin-Film Transistor Applications, Sang-Dae Bae, Soo-Hun Kwon, Hwan-Seok Jeong, Hyuck-In Kwon (Chung-Ang University, Korea) CO ₂ Laser-Induced Breakdown Spectroscopy Applied to Cr Speciation Analysis Using Surfactant, Takuya Matsumoto, Seiji Kitayama, Kazuma Takauchi, Kazuyoshi Kurihara (University of Fukui, Japan)
PO2-49 PO2-50 PO2-51	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of p-Type SnO Thin-Films for Thin-Film Transistor Applications, Sang-Dae Bae, Soo-Hun Kwon, Hwan-Seok Jeong, Hyuck-In Kwon (Chung-Ang University, Korea) CO ₂ Laser-Induced Breakdown Spectroscopy Applied to Cr Speciation Analysis Using Surfactant, Takuya Matsumoto, Seiji Kitayama, Kazuma Takauchi, Kazuyoshi Kurihara (University of Fukui, Japan) Electrocatalytic Activity of Manganese Oxide Modified Carbon Nanotube Supported Platinum Based Catalysts for Ethanol Oxidation, Chatchawan Panrod,
PO2-49 PO2-50 PO2-51	University, Denmark) Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of p-Type SnO Thin-Films for Thin-Film Transistor Applications, Sang-Dae Bae, Soo-Hun Kwon, Hwan-Seok Jeong, Hyuck-In Kwon (Chung-Ang University, Korea) CO ₂ Laser-Induced Breakdown Spectroscopy Applied to Cr Speciation Analysis Using Surfactant, Takuya Matsumoto, Seiji Kitayama, Kazuma Takauchi, Kazuyoshi Kurihara (University of Fukui, Japan) Electrocatalytic Activity of Manganese Oxide Modified Carbon Nanotube Supported Platinum Based Catalysts for Ethanol Oxidation, Chatchawan Panrod, Burapat Inceesungworn, Suwaphid Themsirimongkon, Paralee Weankeaw, Surin Saipanya
PO2-48 PO2-49 PO2-50 PO2-51 PO2-52	Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of p-Type SnO Thin-Films for Thin-Film Transistor Applications, Sang-Dae Bae, Soo-Hun Kwon, Hwan-Seok Jeong, Hyuck-In Kwon (Chung-Ang University, Korea) CO ₂ Laser-Induced Breakdown Spectroscopy Applied to Cr Speciation Analysis Using Surfactant, Takuya Matsumoto, Seiji Kitayama, Kazuma Takauchi, Kazuyoshi Kurihara (University of Fukui, Japan) Electrocatalytic Activity of Manganese Oxide Modified Carbon Nanotube Supported Platinum Based Catalysts for Ethanol Oxidation, Chatchawan Panrod, Burapat Inceesungworn, Suwaphid Themsirimongkon, Paralee Weankeaw, Surin Saipanya (Chiang Mai University, Thailand)
PO2-49 PO2-50 PO2-51	Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of p-Type SnO Thin-Films for Thin-Film Transistor Applications, Sang-Dae Bae, Soo-Hun Kwon, Hwan-Seok Jeong, Hyuck-In Kwon (Chung-Ang University, Korea) CO ₂ Laser-Induced Breakdown Spectroscopy Applied to Cr Speciation Analysis Using Surfactant, Takuya Matsumoto, Seiji Kitayama, Kazuma Takauchi, Kazuyoshi Kurihara (University of Fukui, Japan) Electrocatalytic Activity of Manganese Oxide Modified Carbon Nanotube Supported Platinum Based Catalysts for Ethanol Oxidation, Chatchawan Panrod, Burapat Inceesungworn, Suwaphid Themsirimongkon, Paralee Weankeaw, Surin Saipanya (Chiang Mai University, Thailand) Electrochemical Deposition of ZnO/Magnetic-Metal Hybrid Core/Shell nanowires,
PO2-48 PO2-49 PO2-50 PO2-51 PO2-52	Introduction of Ferroelectric Domain Walls into a BiFeO ₃ Thin Film on a Vicinal SrTiO ₃ (110) Substrate, Yuta Kurokawa, Shota Seto, Seiji Nakashima, Hironori Fujisawa, Masaru Shimizu (University of Hyogo, Japan) Carrier Transport Mechanism in Realistic Operating Condition of p-Channel SnO Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Chan-Yong Jeong, Sang-Dae Bae, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Investigation on Bulk and Interface Trap Densities in p-type High-Mobility Tungsten Diselenide Thin-Film Transistors, Hee-Joong Kim, Sae-Young Hong, Dae-Hwan Kim, Chan-Yong Jeong, Jeong-Hwan Lee, Hyuck-in Kwon (Chung-Ang University, Korea) Optical Properties of Vacuum Evaporated Metal Films on Moth-Eye Structure, Kazunari Shinbo, Yu Tsumura, Chutiparn Lertvachirapaiboon, Yasuo Ohdaira, Akira Baba, Keizo Kato, Futao Kaneko (Niigata University, Japan) Effect of Argon Plasma Surface Treatment on the Physical and Chemical Properties of p-Type SnO Thin-Films for Thin-Film Transistor Applications, Sang-Dae Bae, Soo-Hun Kwon, Hwan-Seok Jeong, Hyuck-In Kwon (Chung-Ang University, Korea) CO ₂ Laser-Induced Breakdown Spectroscopy Applied to Cr Speciation Analysis Using Surfactant, Takuya Matsumoto, Seiji Kitayama, Kazuma Takauchi, Kazuyoshi Kurihara (University of Fukui, Japan) Electrocatalytic Activity of Manganese Oxide Modified Carbon Nanotube Supported Platinum Based Catalysts for Ethanol Oxidation, Chatchawan Panrod, Burapat Inceesungworn, Suwaphid Themsirimongkon, Paralee Weankeaw, Surin Saipanya (Chiang Mai University, Thailand)

	Poster session 3 (June 21, 12:00 - 13:30)
PO3-1	Effects of Element Addition to Perovskite-Type Photovoltaic Devices, Takeo Oku,
	Yuya Ohishi, Atsushi Suzuki (University of Shiga Prefecture, Japan)
PO3-2	Fabrication and Characterization of Perovskite Solar Cells with TiO ₂ Nanoparticle layers,
	Naoki Ueoka ¹ , Takeo Oku ¹ , Atsushi Suzuki ¹ , Hiroki Sakamoto ² , Masahiro Yamada ² ,
	Satoshi Minami ³ , Shinsuke Miyauchi ³ (¹ University of Shiga Prefecture, Japan ² Osaka Gas Co.
	Ltd., Japan ³ Osaka Gas Chemicals Co. Ltd., Japan)
PO3-4	Passivation Effect of Ultra-Thin SiN _x Films Formed by Cat-CVD for Crystalline Silicon
	Surfaces, Hao Song, Keisuke Ohdaira (Japan Advanced Institute of Science and Technology,
	Japan)
	(Withdrawn) Bipolar Resistive Switching of Ag-doped NiO-Based RRAM devices,
	Chia-Hang Cheng, Hsien-Heng Tang, Ricky W. Chuang, Yan-Kuin Su, Thou-Jen Whang
	(National Cheng Kung University, Taiwan)
PO3-6	Tin Monoxide-Based Gallium Nitride Heterostructure Field Effect Transistor (HFET),
	Cheng-Yu Hsieh, Ricky W. Chuang, Shyh-Jer Huang (National Cheng Kung University, Taiwan)
PO3-7	Microstructure Analysis of Spherical Silicon Solar Cells with SnO _x :F Anti-Reflection Films,
	Takeo Oku ¹ , Youichi Kanamori ² , Mikio Murozono ² (¹ University of Shiga Prefecture, Japan
	² Clean Venture 21 Corp., Japan)
PO3-8	Fabrication and Characteriztion of Cs-Doped Perovskite Solar Cells, Naoki Ueoka,
	Takeo Oku, Atsushi Suzuki (University of Shiga Prefecture, Japan)
PO3-9	Study on Comparision of Lamination Interfaces in Organic Light-Emitting Diodes,
	Yuya Ozawa, Shigeki Naka, Hiroyuki Okada (University of Toyama, Japan)
PO3-10	Oriented Thin Films of Mixture of a Low-Band-Gap Polymer and a Fullerene Derivative
	Prepared by Friction Transfer Method, Nobutaka Tanigaki ¹ , Toshiko Mizokuro ¹ ,
	Tetsuhiko Miyadera ¹ , Yousei Shibata ¹ , Tomoyuki Koganezawa ² (¹ National Institute of Advanced
	Industrial Science and Technology, Japan, ² Japan Synchrotron Radiation Research Institute,
	Japan)
PO3-11	Growth of Heavily Nitrogen-Doped Diamond Films, Shinji Ikeda, Tsubasa Matsumoto,
	Tokuda Norio, Takao Inokuma (Kanazawa University, Japan)
PO3-12	Influence of Al/Cu-doped ZnO on Energy Level Variations Fabricated by Sol-Gel Synthesis
	Methods, Leo Chau-Kuang Liau, Yi-Chen Yang (Yuan Ze University, Taiwan)
	(Withdrawn) Air-Processed Semitransparent Organic Solar Cells with Tunable Color,
	Shunjiro Fujii, Yuki Kuwahara, Takeshi Saito (National Institute of Advanced Industrial Science
DOC	and Technology, Japan)
PO3-14	Fabrication of Ferroelectric Nanowire Capacitors by MOCVD, Yohei Takeuchi,
DO2 45	Hironori Fujisawa, Masaru Shimizu, Seiji Nakashima (University of Hyogo, Japan)
PO3-15	Rubrene-Based Ultra-Thin Organic Light-Emitting Diodes, Takumu Koike, Shigeki Naka,
PO3-16	Hiroyuki Okada (University of Toyama, Japan) Evaluation of Electron Injection at Oxide Electrode/Organic Layer Interface Using
FU3-10	Polyethylenimine-Ethoxylated as Electron Injector, Taishi Yoshida, Shigeki Naka,
	Hiroyuki Okada (University Toyama, Japan)
PO3-17	Electronic Structures in Oxide- and Halide-Based Natural Superlattice Structures,
. 55-17	Takahiro Watanabe, Takayuki Makino (University of Fukui, Japan)
PO3-18	Electrochemical Determination of Caffeic Acid in Beverages Using MWCNT/PEDOT:PSS-
. 55 10	Modified Electrodes, Kulrisa Kuntamung, Padchanee Sangthong, Jaroon Jakmunee,
	Kontad Ounnunkad (Chiang Mai University, Thailand)
PO3-19	Change of Phase Transition Temperature on the Bismuth Titanate with Various Doping
-	Ratio Measured by Dielectric Measurement, Tang Rui, Chung Wung Bark (Gachon
	University, Korea)

PO3-20	Ar/O ₂ Flow Ratio Dependence for Hf _{1-x} Zr _x O ₂ Ferroelectric Thin Films Deposited by RF
	Magnetron Sputtering, J. J. Liao ^{1,2} , Q. X. Peng ² , Y. C. Zhou ² , S. Ohmi ¹ (¹ Tokyo Institute of
	Technology, Japan, ² Xiangtan University, China)
PO3-21	The Electronic Planting Technology Utilizing Solar Power Generation and Inorganic
	Material have an Influence on Plant Growth, Atsuko Fukuyama ¹ , Kazuhisa Hasegawa ² ,
	Teruo Hori ¹ , Masaaki Kuzuhara ¹ , Susumu Yonezawa ¹ , Keely Brandon ³ , Yoshiyuki Masumura ⁴ ,
	Daisuke Mori ⁴ , Hiroshi Kanamaru ⁴ (¹ University of Fukui, Japan, ² Ishikawa Prefectural
	University, Japan, ³ OIST, Japan, ⁴ Nihon Shinko Co. Ltd., Japan)
PO3-22	Characteristics of X-ray-Induced Absorption in Various Types of Silica Glasses,
	Hiroki Sakakibara ¹ , Nobu Kuzuu ¹ , Naoya Sato ¹ , Hideharu Horikoshi ² , Yu Arakawa ¹ (¹ University
	of Fukui, Japan, ² Tosoh SGM Corp., Japan)
PO3-23	Effect of Metal Oxides on Graphene Oxide Support for Methanol Oxidation,
	Supannisa Rattanakansang, Burapat Inceesungvorn, Surin Saipanya, Paralee Waenkaew (Chiang
	Mai University, Thailand)
PO3-24	Analysis of THz Plasmonic Superfocusing Mode in Metallic V-Groove Tapered
	Waveguides, Kiwamu Kusama ¹ , Kazuyoshi Kurihara ¹ , Fumiyoshi Kuwashima ² ,
	Osamu Morikawa ³ , Kohji Yamamoto ¹ , Masahiko Tani ¹ (¹ University of Fukui, Japan, ² Fukui
	University of Technology, Japan, ³ Japan Coast Guard Academy, Japan)
PO3-25	Increase in Photo-Voltage of Inverted Polymer Solar Cells by Applying Forward Bias
	under UV-Cut Light Irradiation, Takayuki Kuwabara, Takuji Kusumi, Makoto Karakawa,
	Tetsuya Taima, Kohshin Takahashi (Kanazawa University, Japan)
PO3-26	Experimental Analysis of Pixel-Shrinkage in Organic Light-Emitting Diodes,
	Takuma Tanabe ¹ , Eiki Kondo ¹ , Munehiro Kimura ² , Masahiro Minagawa ¹ (¹ National Institute of
	Technology, Nagaoka College, Japan, ² Nagaoka University of Technology, Japan)
PO3-27	Thermal Conductivity in Suspended h-BN Flake of Variable Shapes, Muhaiminul Islam,
	Imam-Ul-Ferdous, Ashraful Ghani Bhuiyan, Md. Sherajul Islam (Khulna University of Engineering and Technology, Bangladesh)
PO3-28	Temperature Induced Anomalous Photoluminescence of Hybrid Organometal Halide
1 03 20	(CH ₃ NH ₃ PbI ₃) Perovskite, Md. Masud Rana ^{1,2} , Md. Sherajul Islam ² , Ashraful G. Bhuiyan ² ,
	Takayuki Makino ³ (¹ Jessore University of Science and Technology, Bangladesh, ² Khulna
	University of Engineering and Technology, Bangladesh, ³ University of Fukui, Japan)
DO0 00	
PO3-29	Micropatterning of BiFeO ₃ Films by Electron-Beam-Induced Reaction Process, Tadashi Fujii, Osamu Furukawa, Syunsuke Ebi, Tomoaki Karaki (Toyama Prefectural University
	Japan)
PO3-30	Selective Detection of Fe ³⁺ Ions by Dopamine Functionalized Carbon Dots, Peng Shasha,
	Dal Ho Lee, Sang Joon Park (Gachon University, Korea)
PO3-31	Chemical Hole Doping into Atomically Thin Materials Using Boron-Based Oxidant,
	Hirofumi Matsuoka ¹ , Kaito Kanahashi ² , Naoki Tanaka ³ , Yoshiaki Shoji ³ , Masatou Ishihara ⁴ ,
	Masataka Hasegawa ⁴ , Lain-Jong Li ⁵ , Jiang Pu ² , Hiroshi Ito ¹ , Takanori Fukushima ³ ,
	Taishi Takenobu ^{1,2} (¹ Nagoya University, Japan, ² Waseda University, Japan, ³ Tokyo Institute of
	Technology, Japan, ⁴ National Institute of Advanced Industrial Science and Technology, Japan,
	⁵ King Abdullah University of Science and Technology, Saudi Arabia)
PO3-32	ESR Observations of Charge Carrier Dynamics in Semicrystalline Conducting Polymers,
. 55 02	Shinya Kawamura, Ayato Wakamatsu, Hisaaki Tanaka, Taishi Takenobu (Nagoya University,
	Japan)
PO3-33	Fabrication and Characterization of Diamond MOS Diodes Using SiON Films,
	Ryosuke Mikuni, Akihiro Inoue, Tsubasa Matumoto, Norio Tokuda, Takao Inokuma (Kanazawa
	University, Japan)

PO3-34	Characteristics of NdNiO ₃ Synthesized in the Ambient of Oxygen Gas by Using Solid State
	Reaction Method, Sangmo Kim, Tang Rui, Nguyen Thi Nguyen, Chung Wung Bark (Gachon
	University, Korea)
PO3-35	Preparation of Titanium Dioxide Films with Various Crystal Structures Fabricated by Off-
	Axis RF Sputtering for Compact Layers of Solar Cells, Sangmo Kim, Tang Rui,
	Nguyen Thi Nguyen, Chung Wung Bark (Gachon University, Korea)
PO3-36	Microstructure Analysis of Perovskite CH ₃ NH ₃ PbI ₃ Solar Cells Based on X-Ray Diffraction
	Measurements, Yuji Ando, Takeo Oku (University of Shiga Prefecture, Japan)
PO3-37	High Growth Rate (≥ 0.3 mm/h) of Homoepitaxial Diamond (100) Films by Microwave
. 00 01	Plasma CVD, Koichi Ito ¹ , Shunsuke Watanabe ¹ , Tsubasa Matsumoto ¹ , Osamu Ariyada ² ,
	·
	Norio Tokuda ¹ , Takao Inokuma ¹ (¹ Kanazawa University, Japan, ² Arios Inc., Japan)
PO3-38	Long-Term Potential-Induced Degradation Tests for n-Type c-Si-Wafer-Based Photovoltaic
	Cell Modules, Yutaka Komatsu ¹ , Seira Yamaguchi ¹ , Atsushi Masuda ² , Keisuke Ohdaira ¹ (¹ Japan
	Advanced Institute of Science and Technology, Japan, ² National Institute of Advanced Industrial
	Science and Technology, Japan)
PO3-39	Characterization of a Compact SiC Photovoltaic Inverter Equipped with Spherical Si Solar
1 00 00	Cells, Yuji Ando ¹ , Takeo Oku ¹ , Masashi Yasuda ¹ , Kazufumi Ushijima ² , Mikio Murozono ³
	(¹ University of Shiga Prefecture, Japan, ² U-Design, Japan, ³ Clean Venture 21 Corp., Japan)
PO3-40	Losses Investigating of the Si Optical Slab Waveguide, Wildan Panji Tresna ^{1,2} ,
	Ryohei Tsurita ¹ , Takeo Maruyama ¹ (¹ Kanazawa University, Japan, ² Indonesian Institute of
	Sciences, Indonesia)
PO3-41	
FU3-41	Influence of H ₂ O and OH Groups for Devitrification of Silica Glass, Naohiro Horii ¹ ,
	Nobu Kuzuu ² , Naoya Sato ² , Hideharu Horikoshi ³ , Masahiro Ikeda ⁴ , Masaru Aniya ⁵ (¹ National
	Institute of Technology, Fukui College, Japan, ² University of Fukui, Japan, ³ Tosoh SGM Corp.,
	Japan, ⁴ National Institute of Technology, Oita College, Japan, ⁵ Kumamoto University, Japan)
PO3-42	Au Thin Film Formed from Au Nano-Particle Dispersed Water Solution Prepared by
	Solution Plasma Processing for SERS Spectroscopy, Naoki Matsuda, Hirotaka Okabe
	(National Institute of Advanced Industrial Science and Technology, Japan)
PO3-43	Dipolar Magnetism and Electrostatic Repulsion of Colloidal Interacting-Nanoparticle
	System, Suko Bagus Trisnanto, Yoshitaka Kitamoto (Tokyo Institute of Technology, Japan)
PO3-44	Fabrication of Caffeine Imprinted Conducting Polymeric Films via Unconventional
	Colloidal Lithography and Electropolymerization, Seonho Kong, Jin Young Park (Kyungpook
	National University, Korea)
PO3-45	A Control System of Normalization for Photoreflectance Optical Intensity with
	Microcomputer, Eiichi Kobayashi, Takayuki Makino, Akihiro Hashimoto (University of Fukui,
	Japan)
PO3-46	Formation of Defect-Free Diamond (100) Surface by Anisotropic Etching of Solid-Solution
	Reaction of Carbon Into Nickel, Taira Tabakoya, Kazuhiro Nakanishi, Masatsugu Nagai,
	Yutaro Katagiri, Tsubasa Matsumoto, Norio Tokuda, Takao Inokuma (Kanazawa University,
	Japan)
PO3-47	Direct Imprinting of Oxide Precursor Gel for New Fabrication Process of Thin Film
	Transistors, Ken-ichi Haga, Yuusuke Kamiya, Eisuke Tokumitsu (Japan Advanced Institute of
	Science and Technology, Japan)
PO3-48	Effect of Substrate Thermal Resistivity on Breakdown Voltage of AlGaN/GaN HEMTs,
1 00-40	Taisei Yamazaki, Joel T. Asubar, Hirokuni Tokuda, Masaaki Kuzuhara (University of Fukui,
	Japan)
PO3-49	Enhancement of Resistive Switching Behaviour and Ferromagnetism in (Al, N)-Codoped
FU3-49	•
	ZnO Memory Device, Sih-Sian Li ¹ , Yan-Kuin Su ¹ , Yu-Min Hu ² (¹ National Cheng Kung
	University, Taiwan, ² National University of Kaohsiung, Taiwan)

PO3-50	Investigation of Dynamic On-Resistance of Multi-Mesa-Channel AlGaN/GaN HEMTs,
	Joel T. Asubar ¹ , Hirokuni Tokuda ¹ , Tamotsu Hashizume ² , Masaaki Kuzuhara ¹ (¹ University of
	Fukui, Japan, ² Hokkaido University, Japan)
PO3-51	Fabrication of SnS Thin-Film Solar Cells via Co-Evaporation Method, Aimi Yago ¹ ,
	Takashi Kibishi ¹ , Yoji Akaki ² , Shigeyuki Nakamura ³ , Hiroto Oomae ⁴ , Hironori Katagiri ¹ ,
	Hideaki Araki ¹ (¹ NIT, Nagaoka College, Japan, ² NIT, Miyakonojo College, Japan, ³ NIT,
	Tsuyama College, Japan, ⁴ NIT, Kushiro College, Japan)
PO3-52	Oxide Layer Growth at the Surface of Tungsten and Consequences on Hydrogen Transfer
	Processes, Abdelouahab El Kharbachi ^{1,2} , Loïc Marchetti ³ , Frédéric Miserque ³ ,
	Bernard Rousseau ¹ (¹ CEA, SCBM, Laboratoire de Marquage par le Tritium, Farance, ² Institute
	for Energy Technology, Norway, ³ CEA, DEN/DPC, Laboratoire d'Étude de la Corrosion
	Aqueuse, France)
PO3-53	High-Efficiency Perovskite Solar Cells with Enhanced UV Light Stability Based on
	Nanosized Particles as Ferroelectric Absorber Layer, Nguyen Thi Nguyen, Rui Tang,
	Seong Gwan Shin, Sangmo Kim, Hyung Wook Choi and Chung Wung Bark (Gachon University,
	Korea)